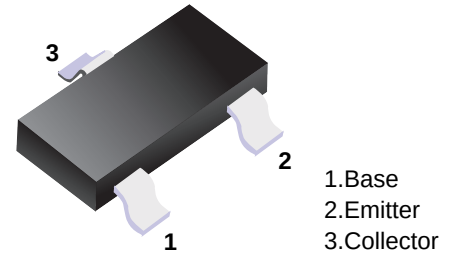


■ PNP Transistors



■ Simplified outline(SOT-23)

■ Features

- Complementary to S9014

■ Absolute Maximum Ratings $T_a = 25^{\circ}\text{C}$

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	V_{CB0}	-50	V
Collector-Emitter Voltage	V_{CE0}	-45	V
Emitter-Base Voltage	V_{EB0}	-5	V
Collector Current -Continuous	I_C	-0.1	A
Collector Power Dissipation	P_C	0.2	W
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55 to 150	$^{\circ}\text{C}$

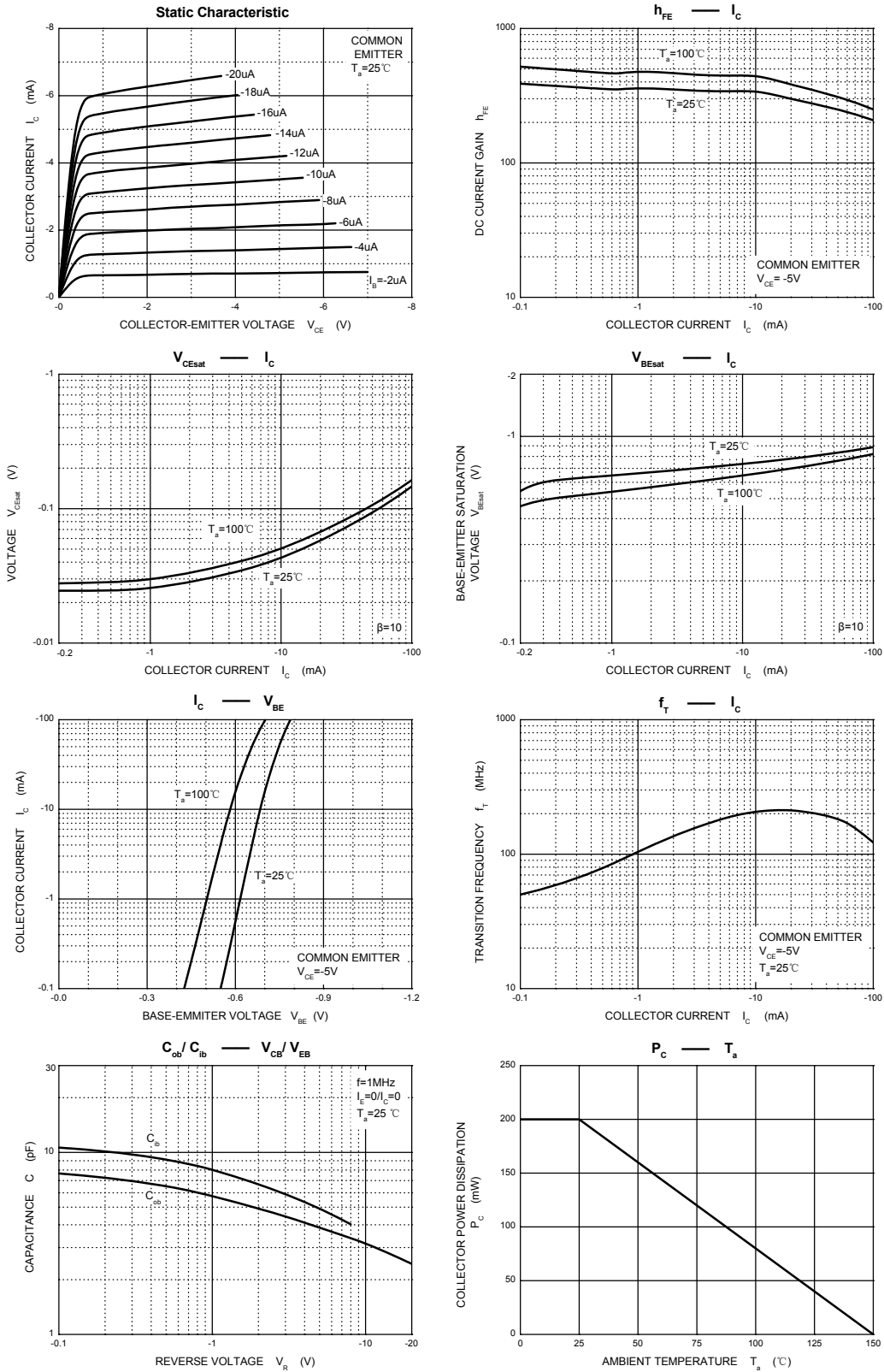
■ Electrical Characteristics $T_a = 25^{\circ}\text{C}$

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V_{CB0}	$I_C = -100\mu\text{A}, I_E = 0$	-50			V
Collector-emitter breakdown voltage	V_{CE0}	$I_C = -1\text{mA}, I_B = 0$	-45			V
Emitter-base Breakdown voltage	V_{EB0}	$I_E = -100\mu\text{A}, I_C = 0$	-5			V
Collector cutoff current	I_{CB0}	$V_{CB} = -50\text{V}, I_E = 0$			-0.1	μA
Emitter cutoff current	I_{EB0}	$V_{EB} = -5\text{V}, I_C = 0$			-0.1	μA
DC current gain	h_{FE}	$V_{CE} = -5\text{V}, I_C = -1\text{mA}$	200		1000	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -100\text{mA}, I_B = -10\text{mA}$			-0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -100\text{mA}, I_B = -10\text{mA}$			-1	V
Transition frequency	f_T	$V_{CE} = -5\text{V}, I_C = -10\text{mA}, f = 30\text{MHz}$	150			MHz

■ h_{FE} Classification

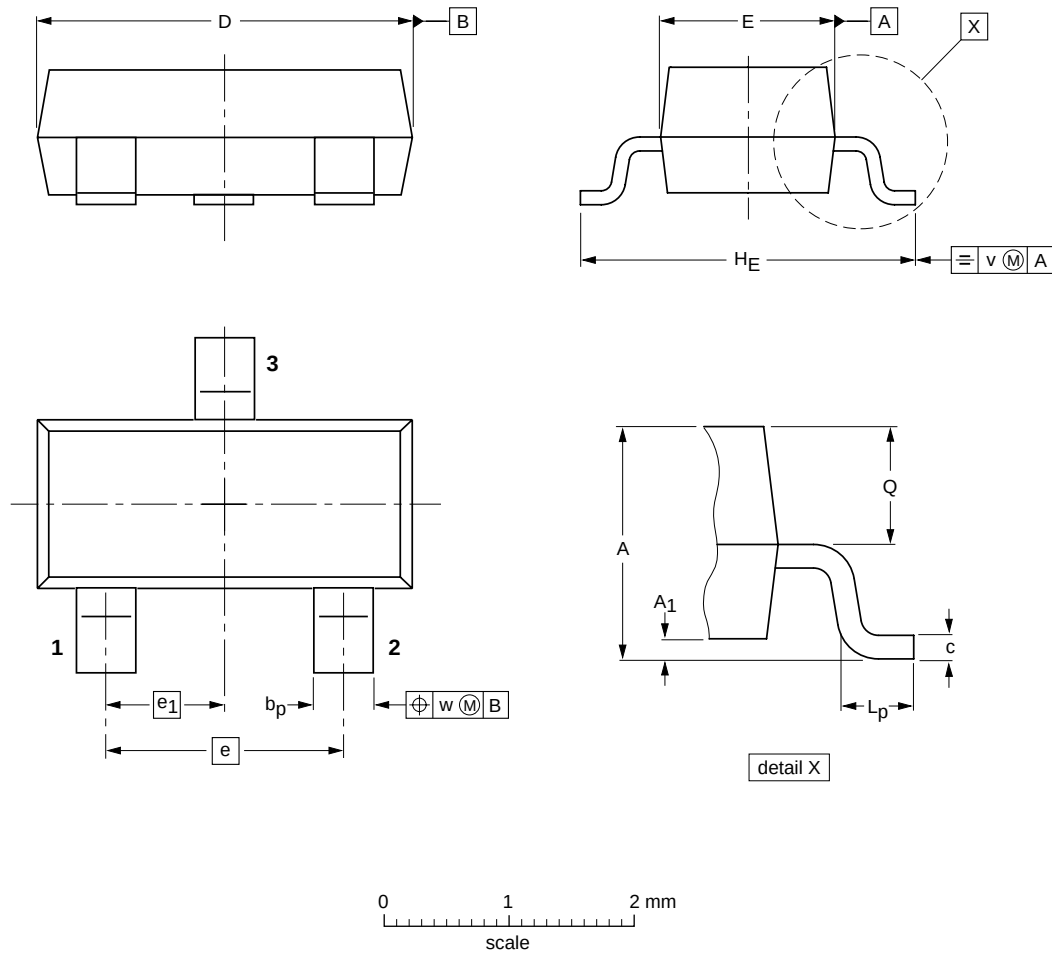
Type	S9015-L	S9015-H
Range	200-450	450-1000
Marking	M6	

■ Typical Characteristics



Package Outline

SOT-23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

Summary of Packing Options

Package	Packing Description	Packing Quantity	Industry Standard
SOT-23	Tape/Reel, 7" reel	3000	EIA-481-1